

TOSHIBA Cmos Linear Integrated Circuit Silicon Monolithic

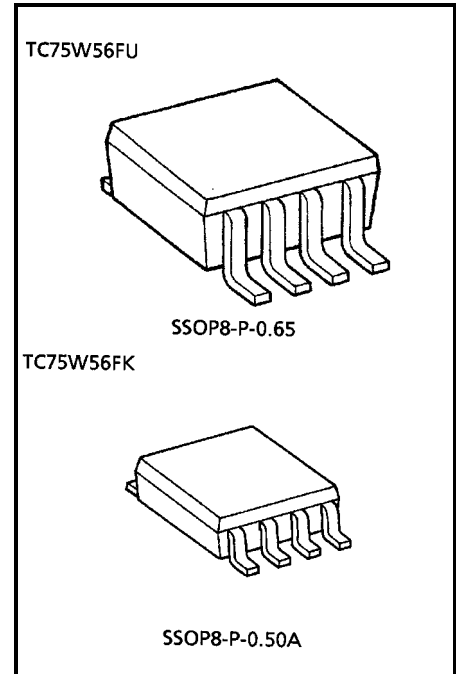
TC75W56FU, TC75W56FK

Dual Comparator

TC75W56 is a CMOS type general-purpose dual comparator capable of single power supply operation and using lower supply currents than the conventional bipolar comparators. Its push-pull output can connect directly to local IC's such as TTL and CMOS circuits.

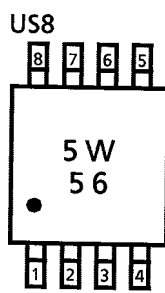
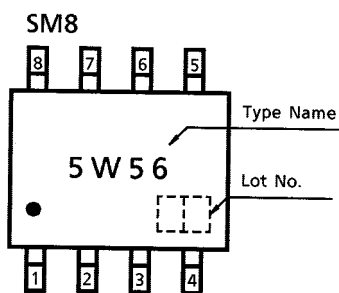
Features

- Low supply current: $I_{DD} = 20\mu A$ (typ.)
- Single power supply operation
- Wide common mode input voltage range: $V_{SS} \sim V_{DD} - 0.9V$
- Push-pull output circuit
- Low input bias current
- Small package

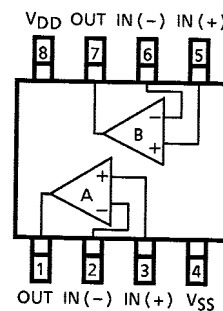


Weight
 SSOP8-P-0.65 : 0.021g (typ.)
 SSOP8-P-0.50A : 0.01g (typ.)

Marking (Top View)



Pin Connection (Top View)



Maximum Ratings (Ta = 25°C)

Characterisctic	Symbol	Rating	N
Supply voltage	V_{DD}, V_{SS}	± 3.5 or 7	V
Differential input voltage	DV_{IN}	± 7	V
Input voltage	V_{IN}	$V_{SS} \sim V_{DD}$	V
Output current	I_{OUT}	± 3.5	mA
Power dissipation	P_D	250 (SM8)	mW
		200 (US8)	
Operating temperature	T_{opr}	-40~85	°C
Storage temperature	T_{stg}	-55~125	°C

Note: Since this product sometimes brings about latchcap, which is peculiar to CMOS devices, note the following points:

- Don't raise the voltage level of I/O pins beyond V_{DD} , nor lower it below V_{SS} . Consider the timing for power supply, too.
- Don't let any abnormal noise enter the device.

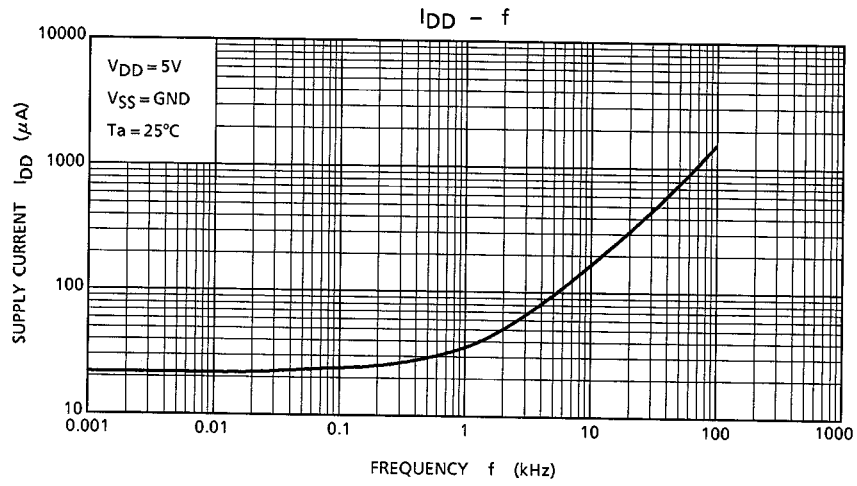
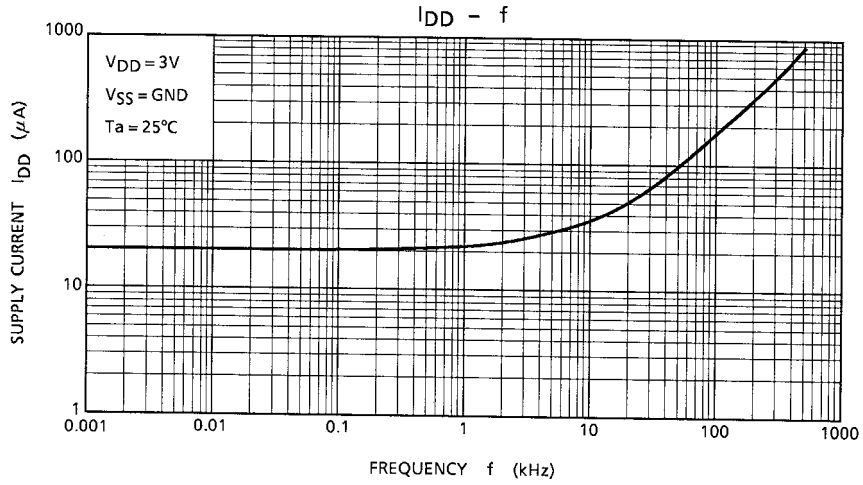
Electrical Characteristics ($V_{DD} = 5V$, $V_{SS} = GND$, $T_a = 25^{\circ}C$)

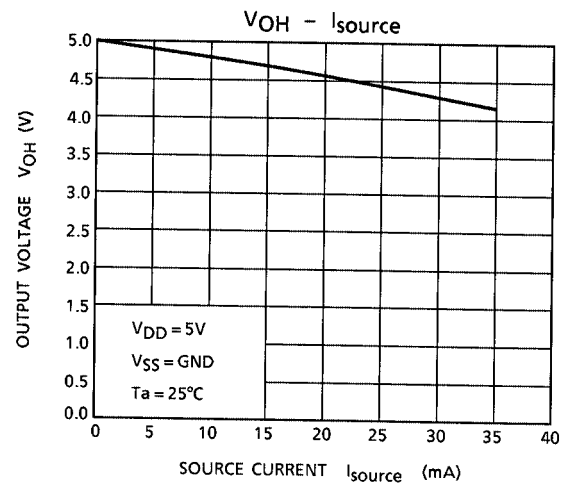
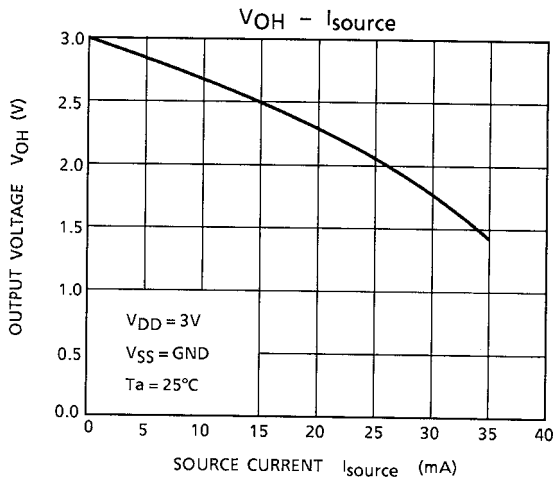
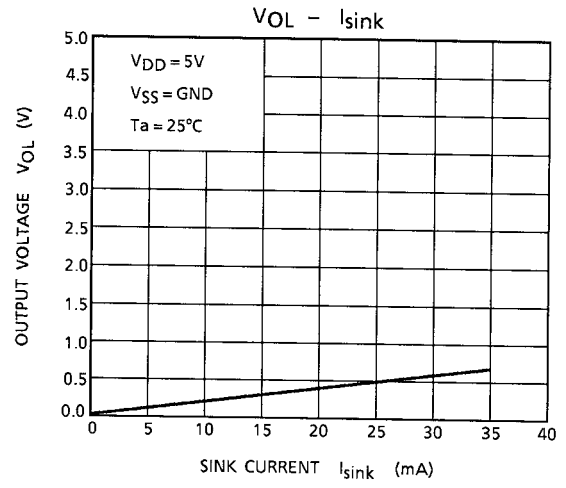
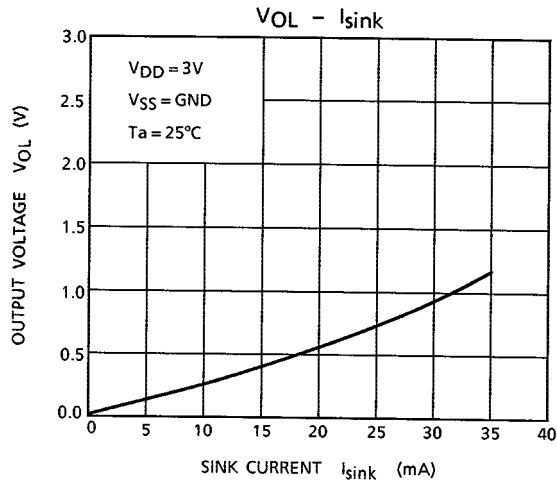
Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input offset voltage	V_{IO}	—	—	—	± 1	± 7	mV
Input offset current	I_{IO}	—	—	—	1	—	pA
Input bias current	I_I	—	—	—	1	—	pA
Common mode input voltage	CMV_{IN}	—	—	0	—	4.1	V
Supply current	I_{DD} (Note)	—	—	—	22	44	μA
Voltage gain	G_V	—	—	—	94	—	dB
Sink current	I_{sink}	—	$V_{OL} = 0.5V$	13	25	—	mA
Source current	I_{source}	—	$V_{OH} = 4.5V$	9	21	—	mA
Output voltage	V_{OL}	—	$I_{sink} = 5.0mA$	—	0.1	0.3	V
	V_{OH}	—	$I_{source} = 5.0mA$	4.7	4.9	—	
Operating supply voltage	V_{DD}	—	—	1.8	—	7.0	V
Propagation delay time (turn on)	t_{PLH} (1)	—	Over drive = 100mV	—	680	—	ns
	t_{PLH} (2)	—	TTL step input	—	500	—	
Propagation delay time (turn off)	t_{PHL} (1)	—	Over drive = 100mV	—	250	—	ns
	t_{PHL} (2)	—	TTL step input	—	380	—	
Response time	t_{TLH}	—	Over drive = 100mV	—	60	—	ns
	t_{THL}	—	Over drive = 100mV	—	8	—	

Electrical Characteristics ($V_{DD} = 3V$, $V_{SS} = GND$, $T_a = 25^{\circ}C$)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input offset voltage	V_{IO}	—	—	—	± 1	± 7	mV
Input offset current	I_{IO}	—	—	—	1	—	pA
Input bias current	I_I	—	—	—	1	—	pA
Common mode input voltage	CMV_{IN}	—	—	0	—	2.1	V
Supply current	I_{DD} (Note)	—	—	—	20	40	μA
Sink current	I_{sink}	—	$V_{OL} = 0.5V$	6	18	—	mA
Source current	I_{source}	—	$V_{OH} = 2.5V$	3	15	—	mA
Output voltage	V_{OL}	—	$I_{sink} = 5.0mA$	—	0.15	0.35	V
	V_{OH}	—	$I_{source} = 5.0mA$	2.65	2.85	—	
Propagation delay time (turn on)	t_{PLH}	—	Over drive = 100mV	—	550	—	ns
Propagation delay time (turn off)	t_{PHL}	—	Over drive = 100mV	—	250	—	ns
Response time	t_{TLH}	—	Over drive = 100mV	—	30	—	ns
	t_{THL}	—	Over drive = 100mV	—	8	—	

Note: Since this product causes an increase in current consumption with a rise in operational frequency, make sure that power consumption does not exceed the allowable dissipation.

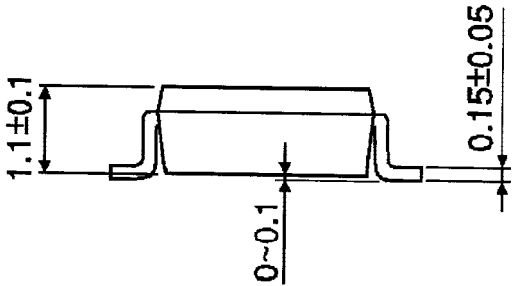
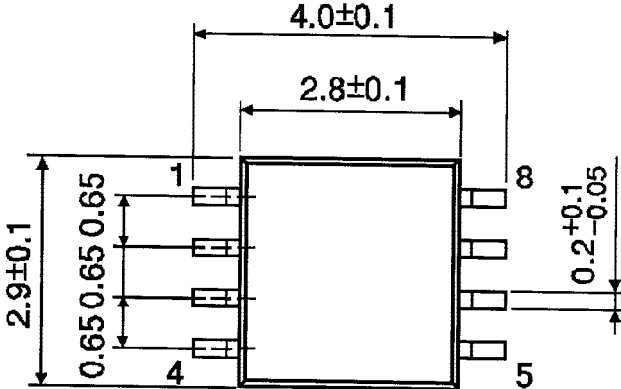




Package Dimensions

SSOP8-P-0.65

Unit: mm

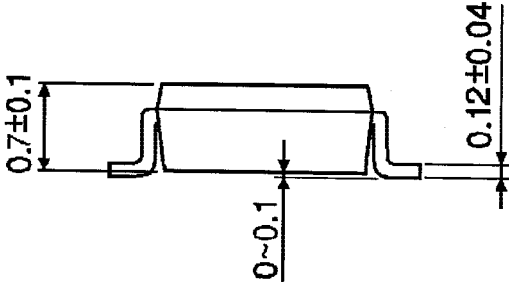
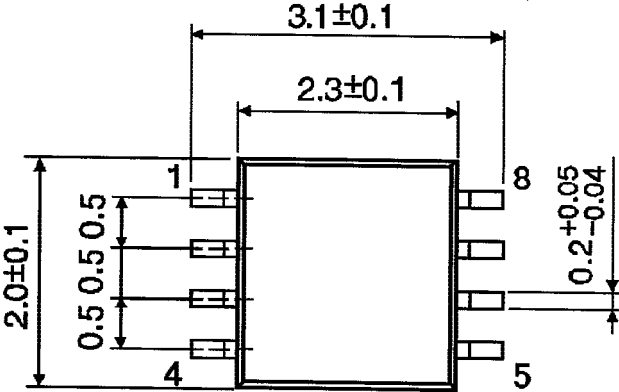


Weight: 0.021g(typ.)

Package Dimensions

SSOP8-P-0.50A

Unit: mm



Weight: 0.01g(typ.)

RESTRICTIONS ON PRODUCT USE

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